

# **2SC3998** — Ultrahigh-Definition CRT Display Horizontal Deflection Output Applications

## **Features**

- High speed (tf=100ns typ).
- High breakdown voltage (VCBO=1500V).
- High reliability (adoption of HVP process).
- · Adoption of MBIT process.

# **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		1500	V
Collector-to-Emitter Voltage	VCEO		800	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		25	А
Collector Current (Pulse)	ICP		50	А
Collector Dissipation	PC		3.5	W
		Tc=25°C	250	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

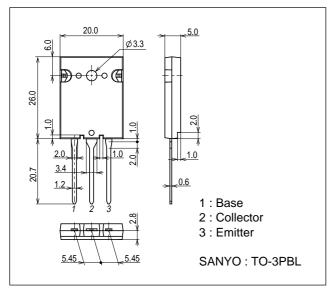
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICES	VCE=1500V			1.0	mA
Collector-to-Emitter Sustain Voltage	V <sub>CEO</sub> (sus)	I <sub>C</sub> =100mA, I <sub>B</sub> =0A	800			V
Emitter Cutoff Current	IEBO	VEB=4V, IC=0A			1.0	mA
Collector Cutoff Current	ICBO	VCB=800V, IE=0A			10	μΑ
DC Current Gain	hFE1	V <sub>CE</sub> =5V, I <sub>C</sub> =1.0A	8		30	
	hFE2	V <sub>CE</sub> =5V, I <sub>C</sub> =20A	4		8	
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=20A, IB=5A			5	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	IC=20A, IB=5A			1.5	V
Storage Time	tstg	IC=12A, IB1=2.4A, IB2=-4.8A			3.0	μs
Fall Time	tf	IC=12A, IB1=2.4A, IB2=-4.8A			0.2	μs

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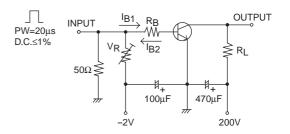
# SANYO Semiconductor Co., Ltd. TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

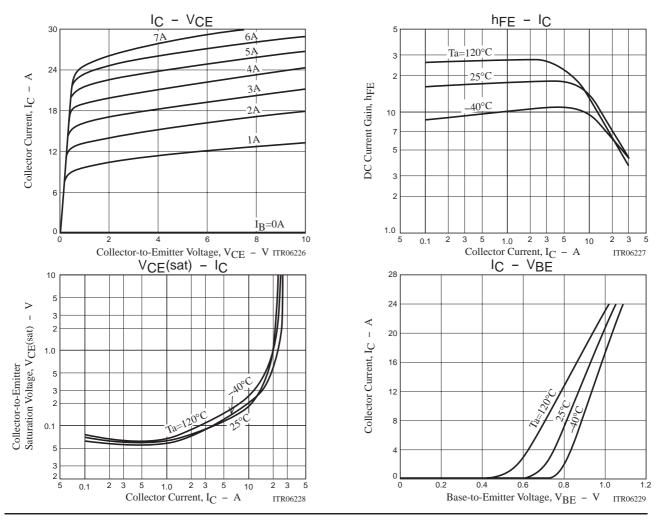
# **Package Dimensions**

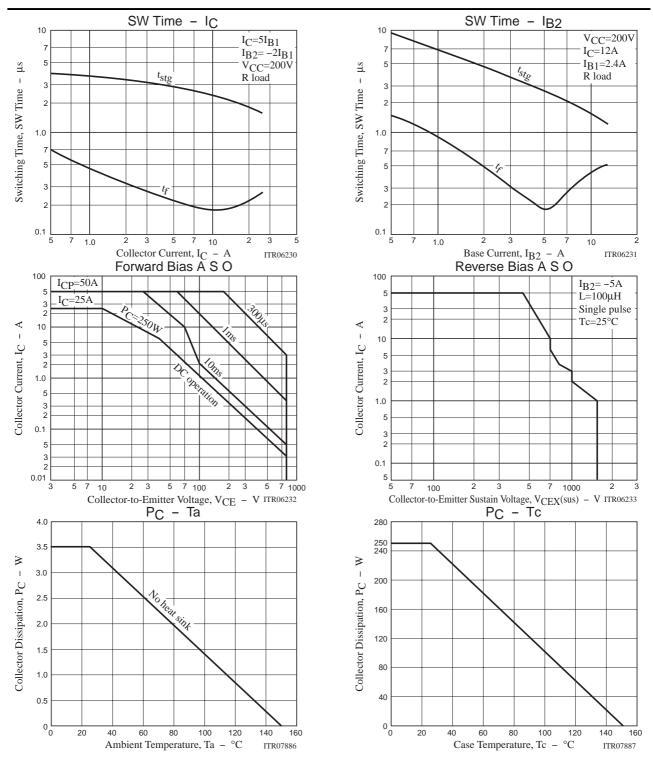
unit : mm (typ) 7502-001



# Switching Time Test Circuit







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